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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/043,534	01/10/2002	Homer Chou	00044X215193	6245	
29050 7590 04/14/2004 PHYLLIS T. TURNER-BRIM, ESQ., LAW DEPARTMENT CABOT MICROELECTRONICS CORPORATION			EXAMINER		
			VINH, LAN		
-	NORTH COMMONS DRIVE		ART UNIT	PAPER NUMBER	
AURORA, IL	. 60504		1765	s	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)	<u></u>			
Office Action Summary		10/043,534	CHOU ET AL.				
		Examiner	Art Unit				
		Lan Vinh	1765				
The MAILING DATE of this Period for Reply	communication app	ears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).							
1)⊠ Responsive to communicat	ion(s) filed on 10 Fa	ehruary 2004					
2a) ☐ This action is FINAL .		action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposition of Claims							
4)⊠ Claim(s) <u>1-27</u> is/are pending in the application.							
4a) Of the above claim(s) is/are withdrawn from consideration.							
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>1-8,13 and 15-27</u> i							
7)⊠ Claim(s) <u>9-12 and 14</u> is/are	•						
8) Claim(s) are subject	=	r election requirement.					
Application Papers							
9) The specification is objected	to by the Examine	r.					
10)☐ The drawing(s) filed on	_ is/are: a)∏ acce	epted or b) \square objected to by the E	Examiner.				
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11)☐ The oath or declaration is ob		-	• •				
Priority under 35 U.S.C. §§ 119 and 120							
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of:							
1. Certified copies of the	priority documents	s have been received.					
2. Copies of the cortified	e priority documents	s have been received in Application ity documents have been receive	on No				
application from the l			d in this National Stage				
		of the certified copies not receive	d.				
13)⊠ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application) since a specific reference was included in the first sentence of the specification or in an Application Data Sheet. 37 CFR 1.78.							
	a) 🔲 The translation of the foreign language provisional application has been received.						
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121 since a specific reference was included in the first sentence of the specification or in an Application Data Sheet. 37 CFR 1.78.							
Attachment(s)							
1) X Notice of References Cited (PTO-892)		4) Interview Summary	(PTO-413) Paper No(s)				
2) Notice of Draftsperson's Patent Drawing 3) Information Disclosure Statement(s) (PT		5) Notice of Informal Pa	atent Application (PTO-152)				

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DETAILED ACTION

Response to Arguments

1. Applicant's argument, see the last paragraph on page 2 and the first and second paragraph on page 3 of the response, filed on February 19, 2004 with respect to the rejection of claims 1-8, 13, 15, 16-18, 20, 22-24, 26 under 35 U.S.C 103(a) have been fully considered and are persuasive. Therefore, the rejection has been withdrawn. However, upon further consideration, a new ground of rejection is made in view of Sun et al (US 6,159,076) reference. A discussion of the rejection follows.

Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1-8, 13, 15, 16-18, 20, 22-24, 26 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nishimoto et al (US 6,582,761) in view of Sun et al (US 6,159,076)

Nishimoto discloses an aqueous dispersion/a system for polishing for CMP comprising: ion-exchanged water (claimed liquid carrier), ammonium persufate (col. 19, lines 24-26), silane coupling agent (col. 8, lines 10-15), polishing pad (col. 24, lines 20-22) and metal abrasive (col. 14, lines 41-44)

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Unlike the instant claimed invention as per claim 1, Nishimoto does not specifically disclose using ammonium oxalate in his aqueous dispersion.

Sun discloses a method for polishing metal using an abrasive CMP solution comprises of ammonium oxalate as a chelating agent(see abstract)

Since Nishimoto is concerned with the step of polishing metal (col 24, lines 5-35), one skilled in the art would have found it obvious to modify Nishimoto's polishing solution by using ammonium oxalate as per Sun because Sun discloses that it is believed that the ammonium oxalate provides the improvement in material removal rate by providing a ligand that bonds strongly with metal (nickel) and moreover is a chelating of nickel/metal (col 8, lines 35-39)

The limitations of claims 2-3, 13 have been discussed above.

Regarding claims 4-5, Nishimoto discloses that the polishing pad is porous polyurethane (col 24, lines 20-21), which reads on a non-abrasive pad

Regarding claims 6-8, Nishimoto discloses using silica /abrasive suspended in an aqueous dispersion (col 14, lines 41-43)

Regarding claim 15, Nishimoto discloses that the pH of the aqueous dispersion is from 2-9 (col 10, lines 14-15)

Regarding claims 16, 22, Nishimoto discloses polishing a portion of the substrate using the aqueous dispersion (col 27, lines 20-22)

Regarding claims 17-18, 20, 23-24, 26, Nishimoto discloses forming working film of silicon oxide, copper, tantalum (col 17, lines 8-17)

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4. Claims 19, 21, 25, 27 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nishimoto et al (US 6,582,761) in view of Sun et al (US 6,159,076) and further in view of Ni (US 6,503,766)

Nishimoto as modified by Sun has been discussed above. Unlike the instant claimed inventions as per claims 19, 21, 25, 27, Nishimoto and Sun do not disclose the specific removal rate ratio of the layer although Nishimoto discloses polishing a film composed of a lower dielectric layer (col 29, lines 35-37)

Ni, in a method for CMP, discloses that a polishing rate can be optimized by adjusting a polishing parameter such as polishing agent flow (col 6, lines 3-7)

Hence, one skilled in the art would have found it obvious to modify Nishimoto and Sun to adjust the polishing agent flow to optimize the removal rate because Ni discloses that the polishing removal rate is a result effective variable in the same field of endeavor.

Allowable Subject Matter

5. Claims 9-12, 14 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter:

No prior art of record discloses using ureidopropyltrimethoxylane as a hydroxy coupling agent in a polishing solution.

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6. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Sasaki (US 5,226,930) discloses a polishing solution comprises silica and silane (see abstract)

Conclusion

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Lan Vinh whose telephone number is 571 272 1471. The examiner can normally be reached on M-F 8:30-5:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine Norton can be reached on 571 272 1465. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

April 12, 2004